IAP6 Rec'd PCT/PTO 19 JUL 2006

APPLICATION DATA SHEET

Electronic Version v14 Stylesheet Version v14.1

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22204

22204

Application Information:

Title of Invention:

THIN FILM TRANSISTOR AND DISPLAY DEVICE, AND

METHOD FOR MANUFACTURING THEREOF

Application Type:

regular, utility

Attorney Docket Number: 740756-2993

Botanic Information:

Publication Information:

Suggested Figure for Publication -

Suggested Classification -

Suggested Technology Center -

Total Number of Drawing Sheets -

Representative Information:

practitioner(s) at Customer Number:

22204

22204

as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.

Domestic Priority Information:

This is a National Stage of JP application number PCT/JP2005/002681, filed 2005-02-15, now Pending.

Foreign Priority Information:

Doc.No:2004-040499; Country - JP; Date: 2004-02-17 us-priority-claimed

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